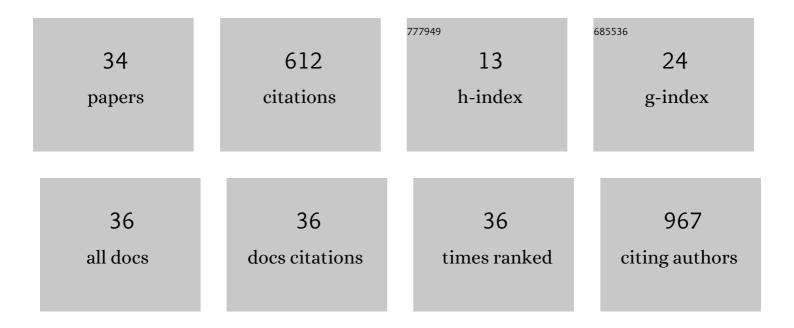
## Jianhui Chen Chen

List of Publications by Year in descending order

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| # | Article   | IF   | CITATIONS |
|---|---|------|-----------|
| 1 | First-principles study of polymer-passivated silicon nanowire outer-shell defects. Physical Chemistry<br>Chemical Physics, 2022, 24, 11169-11174.   | 1.3  | 1         |
| 2 | Considerably Improved Photovoltaic Performances of ITO/Si Heterojunction Solar Cells by<br>Incorporating Hydrogen Into Near-Interface Region. IEEE Journal of Photovoltaics, 2022, 12, 1102-1108. | 1.5  | 2         |
| 3 | Carbon Nanotubes for Photovoltaics: From Lab to Industry. Advanced Energy Materials, 2021, 11, 2002880.   | 10.2 | 59        |

4 Carbon Nanotubes: Carbon Nanotubes for Photovoltaics: From Lab to Industry (Adv. Energy Mater.) Tj ETQq0 0 0 rgBT/Overlock 10 Tf 5

| -  |  | 10.2 | -  |
|----|--|------|----|
| 5  | Solution processable in situ passivated silicon nanowires. Nanoscale, 2021, 13, 11439-11445.   | 2.8  | 3  |
| 6  | Stable Organic Passivated Carbon Nanotube–Silicon Solar Cells with an Efficiency of 22%. Advanced Science, 2021, 8, e2102027.  | 5.6  | 12 |
| 7  | Ferroelectric-like organic–inorganic interfaces. Journal of Materials Chemistry C, 2020, 8, 15677-15684.   | 2.7  | 4  |
| 8  | A Polymer/Carbonâ€Nanotube Ink as a Boronâ€Dopant/Inorganicâ€Passivation Free Carrier Selective Contact<br>for Silicon Solar Cells with over 21% Efficiency. Advanced Functional Materials, 2020, 30, 2004476. | 7.8  | 29 |
| 9  | Conductive Holeâ€Selective Passivating Contacts for Crystalline Silicon Solar Cells. Advanced Energy<br>Materials, 2020, 10, 1903851.  | 10.2 | 28 |
| 10 | Front and Backâ€Junction Carbon Nanotube‣ilicon Solar Cells with an Industrial Architecture.<br>Advanced Functional Materials, 2020, 30, 2000484.  | 7.8  | 33 |
| 11 | Zn(O,S)-based electron-selective contacts with tunable band structure for silicon heterojunction solar cells. Journal of Materials Chemistry C, 2019, 7, 4449-4458.  | 2.7  | 16 |
| 12 | Establishment of a novel functional group passivation system for the surface engineering of c-Si<br>solar cells. Solar Energy Materials and Solar Cells, 2019, 195, 99-105.                                    | 3.0  | 16 |
| 13 | Low work function intermetallic thin film as a back surface field material for hybrid solar cells.<br>Solar Energy, 2018, 162, 397-402.  | 2.9  | 8  |
| 14 | Hafnium Thin Film as a Rear Metallization Scheme for Polymer/Silicon Hybrid Solar Cells. Physica<br>Status Solidi - Rapid Research Letters, 2018, 12, 1800089.   | 1.2  | 6  |
| 15 | ZnS thin film functionalized as back surface field in Si solar cells. Materials Science in Semiconductor Processing, 2018, 74, 309-312.  | 1.9  | 27 |
| 16 | Vacuum-Free, Room-Temperature Organic Passivation of Silicon: Toward Very Low Recombination of<br>Micro-/Nanotextured Surface Structures. ACS Applied Materials & Interfaces, 2018, 10, 44890-44896.           | 4.0  | 23 |
| 17 | Polymer/Si Heterojunction Hybrid Solar Cells with Rubrene:DMSO Organic Semiconductor Film as an Electron-Selective Contact. Journal of Physical Chemistry C, 2018, 122, 23371-23376.                           | 1.5  | 13 |
| 18 | Influence of metals for rear metallization on c-Si solar cells. Journal of Materials Science: Materials<br>in Electronics, 2018, 29, 20312-20318.  | 1.1  | 0  |

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| #  | Article   | IF  | CITATIONS |
|----|---|-----|-----------|
| 19 | Electron-Selective Epitaxial/Amorphous Germanium Stack Contact for Organic-Crystalline Silicon<br>Hybrid Solar Cells. ACS Applied Energy Materials, 2018, 1, 4899-4905.   | 2.5 | Ο         |
| 20 | V oc transient in silicon heterojunction solar cells with µc-SiOx:H window layers. Journal Physics D:<br>Applied Physics, 2018, 51, 305501.   | 1.3 | 1         |
| 21 | Silicon surface passivation by polystyrenesulfonate thin films. Applied Physics Letters, 2017, 110, .   | 1.5 | 28        |
| 22 | Magnesium thin film as a doping-free back surface field layer for hybrid solar cells. Applied Physics<br>Letters, 2017, 110, .  | 1.5 | 27        |
| 23 | Improving the Passivation Stability of a Polymer Thin Film on Si by the Introduction of<br>MoO <sub>3</sub> Nanoparticles Into the Polymer Matrix (Phys. Status Solidi RRL 9/2017). Physica<br>Status Solidi - Rapid Research Letters, 2017, 11, 1770347. | 1.2 | 1         |
| 24 | Ultra-thin MoOx as cathode buffer layer for the improvement of all-inorganic CsPbIBr2 perovskite solar cells. Nano Energy, 2017, 41, 75-83.   | 8.2 | 190       |
| 25 | Single‣ide Heterojunction Solar Cell with Microcrystalline Silicon Oxide Emitter and Diffused Back<br>Surface Field. Physica Status Solidi (A) Applications and Materials Science, 2017, 214, 1700193.  | 0.8 | 5         |
| 26 | Polymer Thin Films for Antiâ€Reflection and Passivation on the Front Surface of Interdigitated Back<br>Contact c‧i Solar Cell. Solar Rrl, 2017, 1, 1700079.   | 3.1 | 9         |
| 27 | Polymer Thin Films for Antiâ€Reflection and Passivation on the Front Surface of Interdigitated Back<br>Contact câ€Si Solar Cell (Solar RRL 7â^2017). Solar Rrl, 2017, 1, 1770125.   | 3.1 | 1         |
| 28 | Improving the Passivation Stability of a Polymer Thin Film on Si by the Introduction of<br>MoO <sub>3</sub> Nanoparticles Into the Polymer Matrix. Physica Status Solidi - Rapid Research<br>Letters, 2017, 11, 1700206.                                  | 1.2 | 4         |
| 29 | Achievement of two logical states through a polymer/silicon interface for organic-inorganic hybrid memory. Applied Physics Letters, 2017, 111, 191601.  | 1.5 | 6         |
| 30 | On the light-induced enhancement in photovoltaic performance of PEDOT:PSS/Si organic-inorganic hybrid solar cells. Applied Physics Letters, 2017, 111, 183904.  | 1.5 | 13        |
| 31 | Electrochemical grafting passivation of silicon via electron transfer at polymer/silicon hybrid interface. Electrochimica Acta, 2017, 247, 826-834.   | 2.6 | 29        |
| 32 | Self-formed point-contact PERC solar cells. Zhongguo Kexue Jishu Kexue/Scientia Sinica Technologica,<br>2017, 47, 965-971.  | 0.3 | 0         |
| 33 | Control of epitaxial growth at a-Si:H/c-Si heterointerface by the working pressure in PECVD. Chinese Physics B, 2016, 25, 118801.   | 0.7 | 0         |
| 34 | The Reverse Lateral Photovoltaic Effect in Boron-Diffused Si p-n Junction Structure. IEEE Electron Device Letters, 2016, 37, 201-204.   | 2.2 | 14        |